

# 2ST1480 2ST2480

## Complementary power transistors

Preliminary data

#### Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Fully insulated package

### **Applications**

- Voltage regulation
- Computer and peripheral equipment
- Audio amplifier
- Relay driver

### Description

The devices are manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

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#### Figure 1. Internal schematic diagrams



#### Table 1. Device summary

Order codes	Marking	Package	Packaging	
2ST1480	2ST1480	SOT-32EP	Bag	
2ST2480	2ST2480	301-3211	Dag	

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This is preliminary information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

# 1 Absolute maximun rating

Table 2.	Absolute	maximum	ratings
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			Value	
Symbol	Parameter	NPN	2ST1480	Unit
		PNP	2ST2480	
$V_{CBO}$	Collector-base voltage $(I_E = 0)$		80	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )		80	V
$V_{\text{EBO}}$	Emitter-base voltage ( $I_C = 0$ )		5	V
Ι <sub>C</sub>	Collector current		4	А
I <sub>CM</sub>	Collector peak current		8	А
Ι <sub>Β</sub>	Base current		0.4	А
P <sub>tot</sub>	Total dissipation at $T_c \le 25 \text{ °C}$		20	W
T <sub>stg</sub>	Storage temperature		-65 to 150	°C
ТJ	Max. operating junction temperature		150	°C

#### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction-case Max	6.3	°C/W

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## 2 Electrical characteristics

 $T_{case} = 25 \ ^{\circ}C$ ; unless otherwise specified.

Symbol	Parameter	Test cor	nditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CE</sub> = 80 V				30	μA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V				100	μA
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage ( $I_B = 0$ )	l <sub>C</sub> = 50 mA		80			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = 3 A	I <sub>B</sub> = 300 mA			0.4	V
$V_{BE(on)}^{(1)}$	Base-emitter on voltage	I <sub>C</sub> = 3 A	$V_{CE} = 5 V$		0.8	1	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_{C} = 0.5 \text{ A}$ for 2ST1480 for 2ST2480 $I_{C} = 3 \text{ A}$	V <sub>CE</sub> = 5 V V <sub>CE</sub> = 5 V	120 120 15		240 300	
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = 0.5 A	$V_{CE} = 5 V$		130		MHz
C <sub>CBO</sub>	Collector-base capacitance $(I_E = 0)$	V <sub>CB</sub> = 10 V	f = 1 MHz		60		pF

 Table 4.
 Electrical characteristics

1. Pulse test: pulse duration  $\leq$  300 µs, duty cycle  $\leq$  2 %

Note: For PNP type voltage and current are negative.

## www.Data **2 1**4U.com **Electrical characteristic (curves)**



## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

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	SOT-32FP mechanical data		
DIM.	MIN.	ТҮР	MAX.
Α	3.00		3.40
A1	1.80		2.20
b	0.66		0.86
b1	1.17		1.37
С	0.45		0.60
D	7.80		8.20
E	10.80		11.20
е		2.28	
e1	4.46		4.66
L	15.30		15.70
L1	1.30		1.50
Р	4.04		4.24
ø1	2.90		3.10
ø2	3.10		3.30



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# 4 Revision history

Table 5.Document revision history

Date	Revision	Changes
09-Oct-2009	1	Initial release.

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